

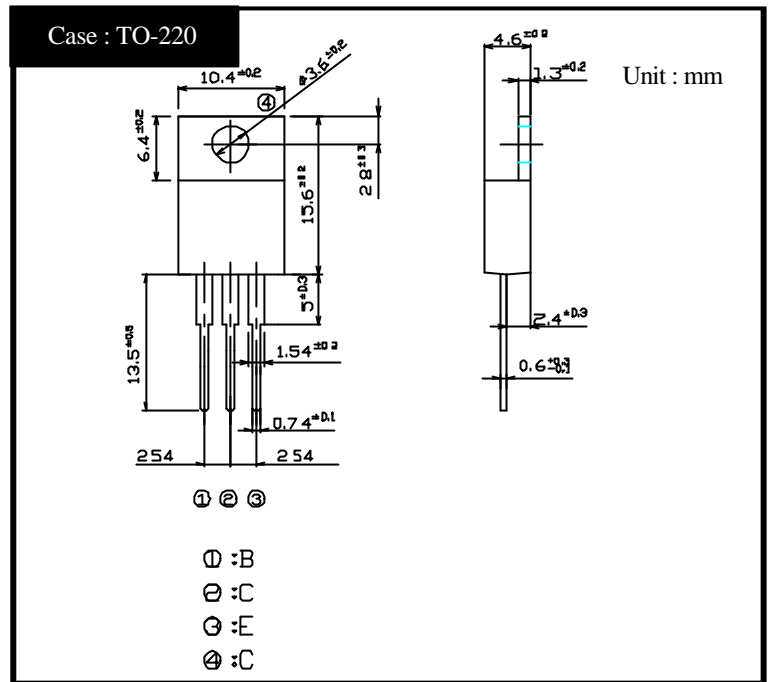
SHINDENGEN

Darlington Transistor

2SD1022
(T5L10)

5A NPN

OUTLINE DIMENSIONS



RATINGS

Absolute Maximum Ratings

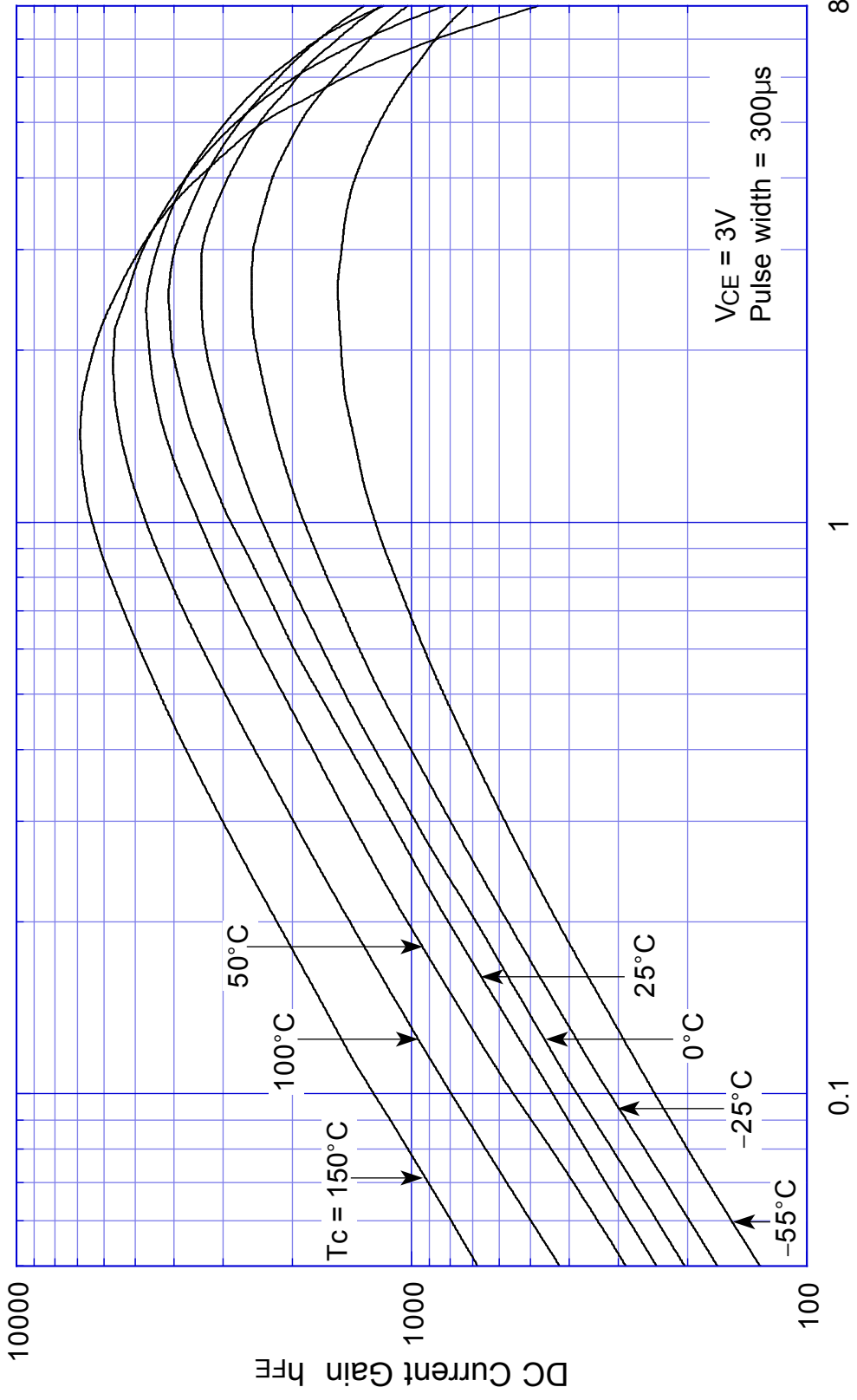
Item	Symbol	Conditions	Ratings	Unit
Storage Temperature	T_{stg}		-55 ~ +150	
Junction Temperature	T_j		+150	
Collector to Base Voltage	V_{CBO}		100	V
Collector to Emitter Voltage	V_{CEO}		100	V
Emitter to Base Voltage	V_{EBO}		7	V
Collector Current DC	I_C		5	A
Collector Current Peak	I_{CP}		8	A
Base Current DC	I_B		0.5	A
Base Current Peak	I_{BP}		1	A
Total Transistor Dissipation	P_T	$T_C = 25$	30	W
Mounting Torque	TOR	(Recommended torque : 0.3N·m)	0.5	N·m

Electrical Characteristics ($T_C=25$)

Item	Symbol	Conditions	Ratings	Unit
Collector Cutoff Current	I_{CBO}	$V_{CB} = 100V$	Max 0.1	mA
	I_{CEO}	$V_{CE} = 100V$	Max 0.1	
Emitter Cutoff Current	I_{EBO}	$V_{EB} = 7V$	Max 5	mA
DC Current Gain	h_{FE}	$V_{CE} = 3V, I_C = 3A$	Min 1,500	
			Max 30,000	
Collector to Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = 3A$	Max 1.5	V
Base to Emitter Saturation Voltage	$V_{BE(sat)}$	$I_B = 3mA$	Max 2.0	V
Thermal Resistance	θ_{jC}	Junction to case	Max 4.17	/W
Transition Frequency	f_T	$V_{CE} = 10V, I_C = 0.5A$	TYP 20	MHz
Turn on Time	t_{on}	$I_C = 5A$ $I_{B1} = I_{B2} = 5mA$ $R_L = 5$ $V_{BB2} = 4V$	Max 2	μs
Storage Time	t_s		Max 5	
Fall Time	t_f		Max 3	

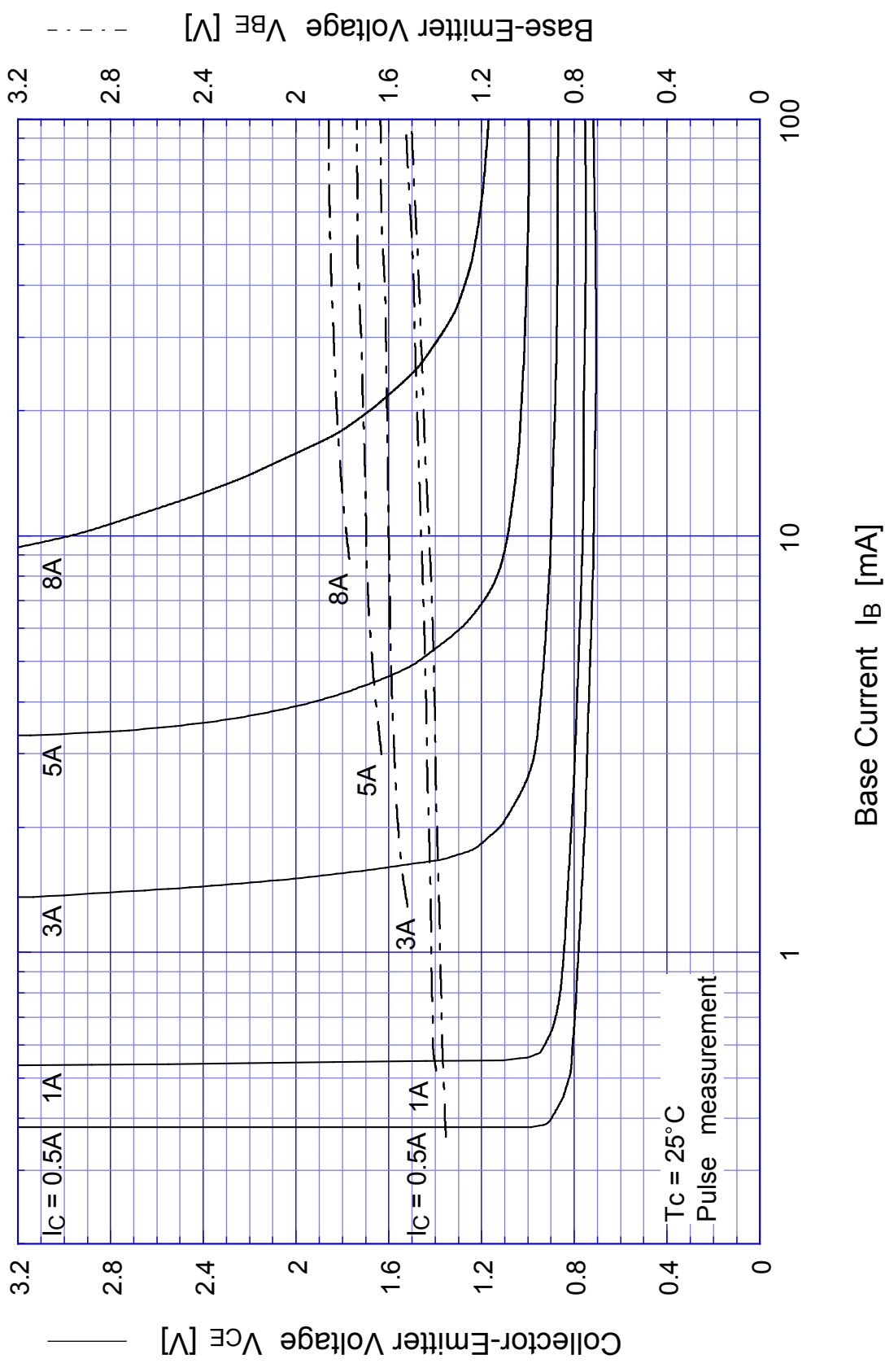
2SD1022

$h_{FE} - I_C$



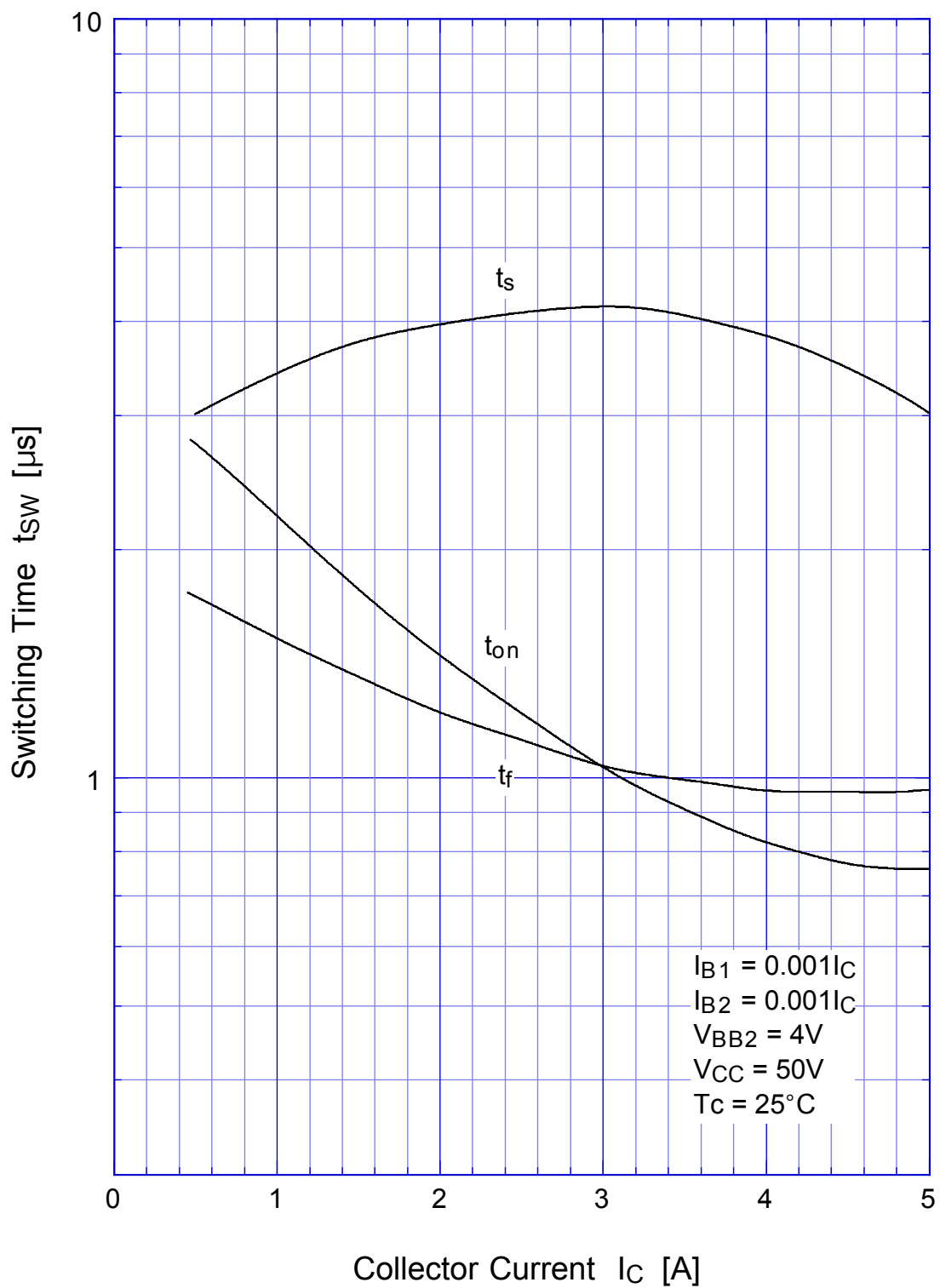
Collector Current I_C [A]

2SD1022 Saturation Voltage



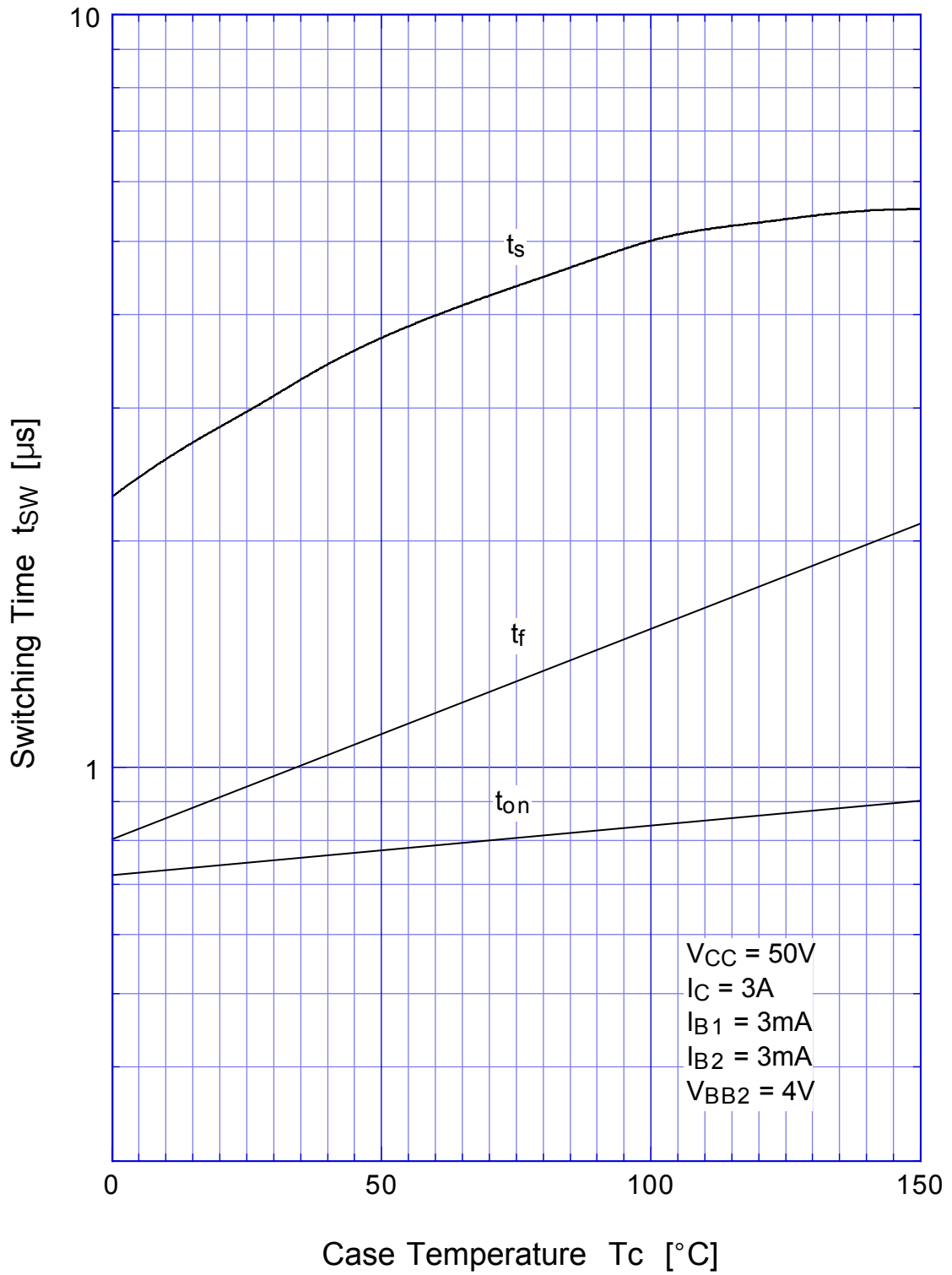
2SD1022

Switching Time - I_C

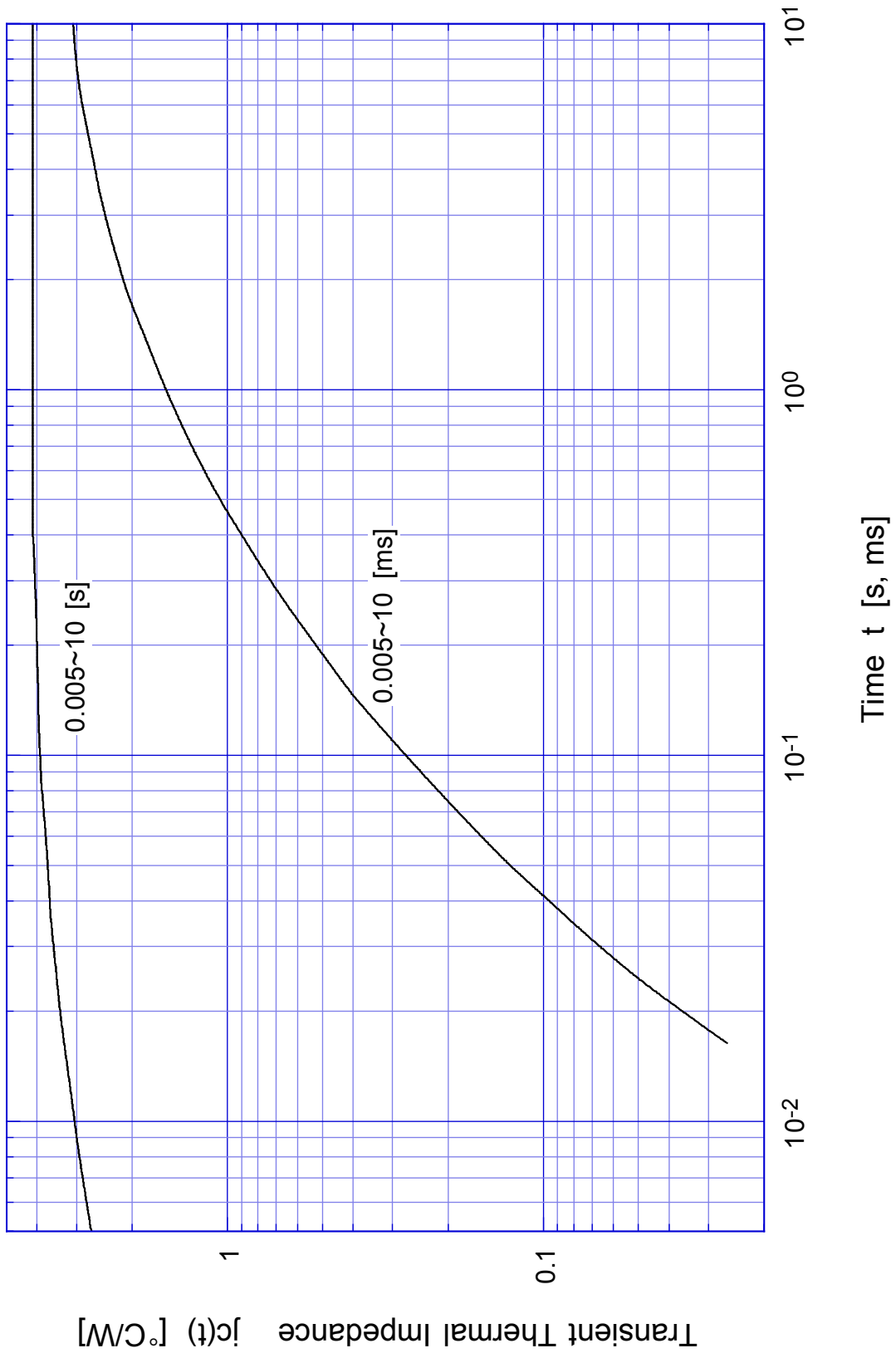


2SD1022

Switching Time - Tc

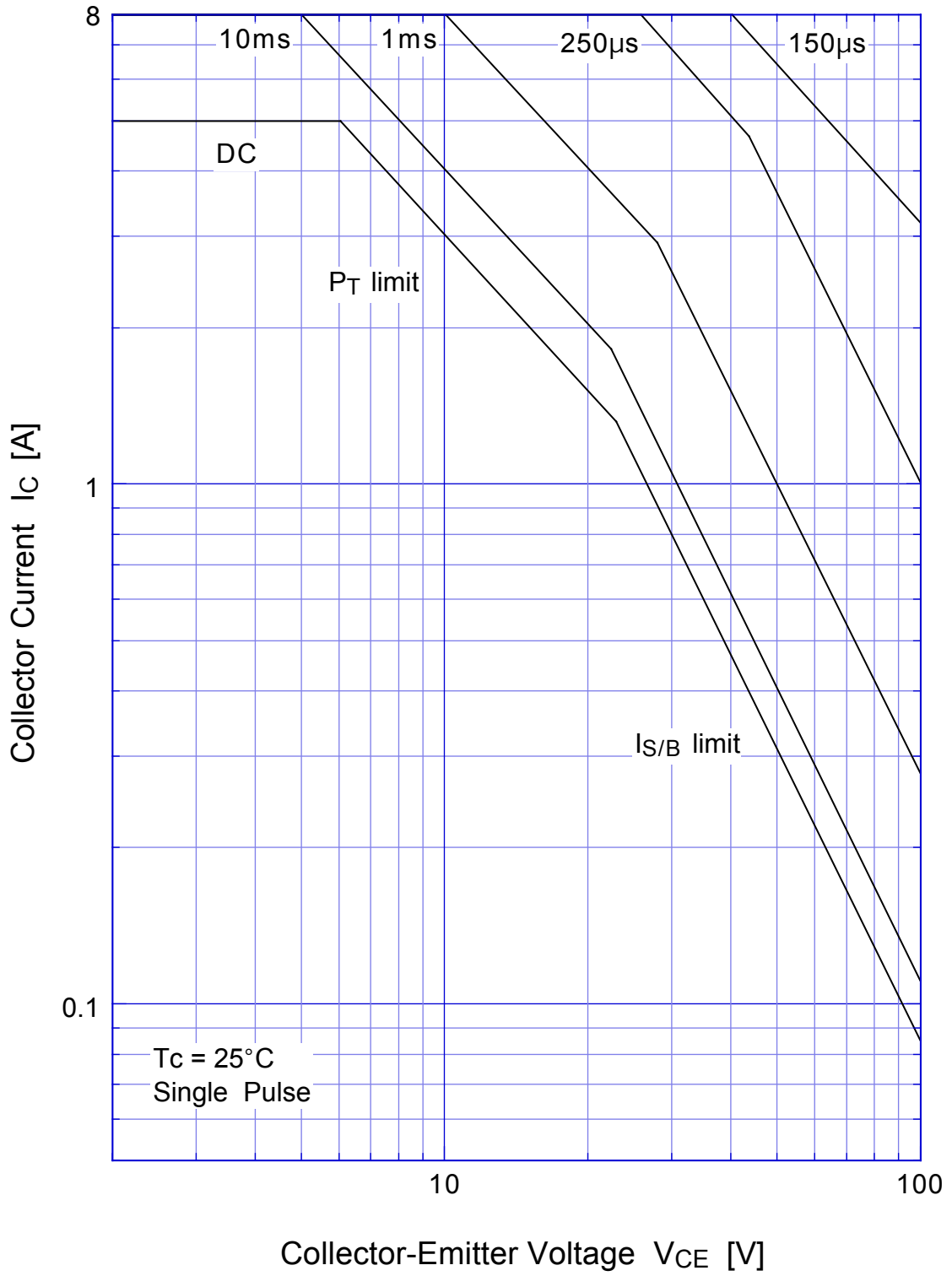


2SD1022 Transient Thermal Impedance



2SD1022

Forward Bias SOA



2SD1022 Collector Current Derating

